

Silicon Schottky Barrier Diode for System Protection



ADE-208-111C (Z) Rev. 3 May 1995

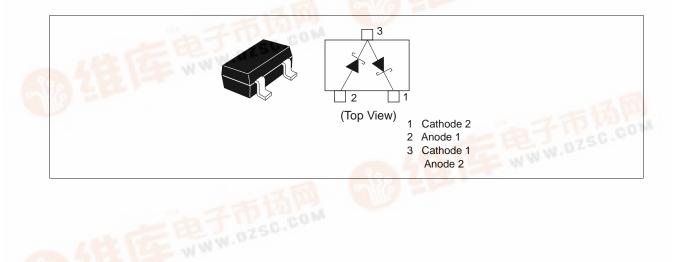
Features

- HSM126S which is connected in series configuration enable to protect electric systems from missoperation against external + and – surge.
- Low V_F and low leakage current.
- MPAK package is suitable for high density surface mounting and high speed assembly.

Ordering Information

Type No.	Laser Mark	Package Code	
HSM126S	S14	MPAK	PD)
		E BJ DZSC.C	00

Pin Arrangement





Absolute Maximum Ratings $(Ta = 25^{\circ}C)^{*3}$

Symbol	Value	Unit	
V _{RRM}	20	V	
l _o *1	200	mA	
I _{FSM} * ²	2	А	
Tj	125	°C	
Tstg	-55 to +125	°C	
	V _{RRM} I ₀ * ¹ I _{FSM} * ² Tj	V_{RRM} 20 I_0^{*1} 200 I_{FSM}^{*2} 2 Tj 125	V _{RRM} 20 V I ₀ *1 200 mA I _{FSM} *2 2 A Tj 125 °C

Notes: 1. Sine wave, Two device total

2. 50Hz half sine wave 1 pulse

3. Per one device

Electrical Characteristics (Ta = 25°C)*

ltem	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse current	I _R		_	2.0	μΑ	$V_{R} = 5V$
Forward voltage	V _F	—	—	0.35	V	$I_F = 10 \text{mA}$
Capacitance	С		40	_	pF	$V_{R} = 0V, f = 1MHz$

Note: Per one device

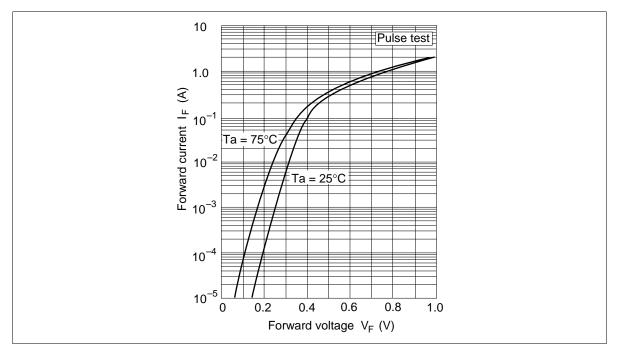


Fig.1 Forward current Vs. Forward voltage

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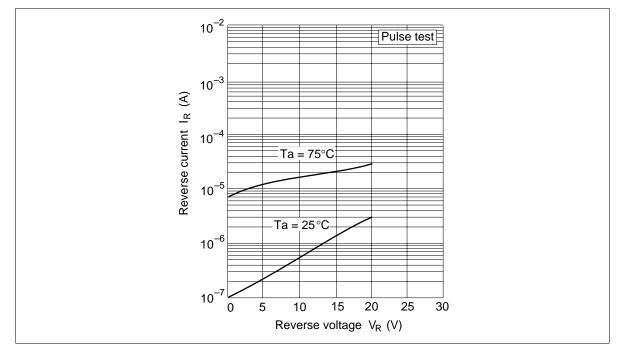


Fig.2 Reverse current Vs. Reverse voltage

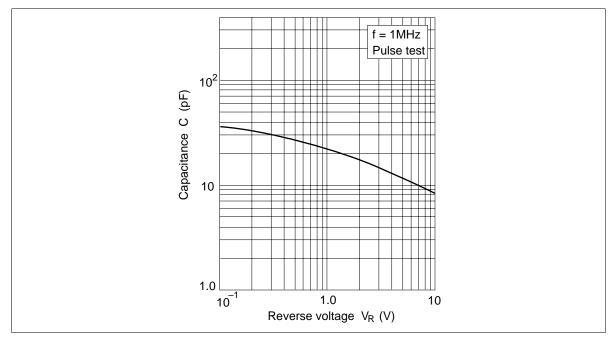
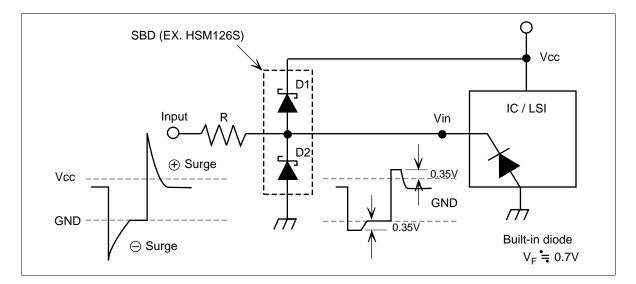


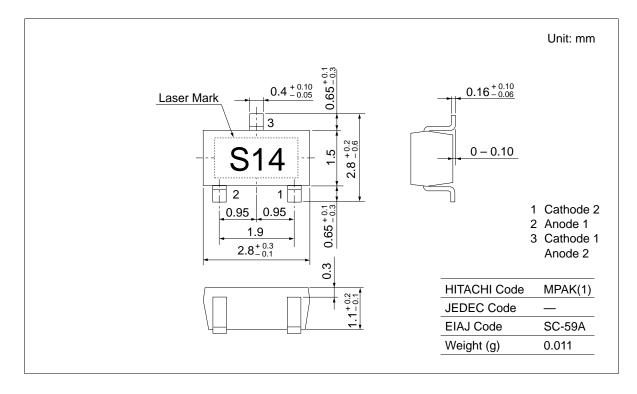
Fig.3 Capacitance Vs. Reverse voltage

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Example of application circuite



Package Dimensions



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